
2SC3127, 2SC3128, 2SC3510

Silicon NPN Epitaxial

HITACHI

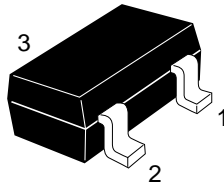
Application

UHF/VHF wide band amplifier

Outline

MPAK

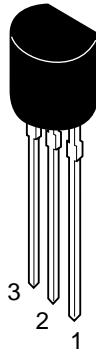
2SC3127



- 1. Emitter
- 2. Base
- 3. Collector

TO-92 (2)

2SC3128, 2SC3510



1. Base
2. Emitter
3. Collector

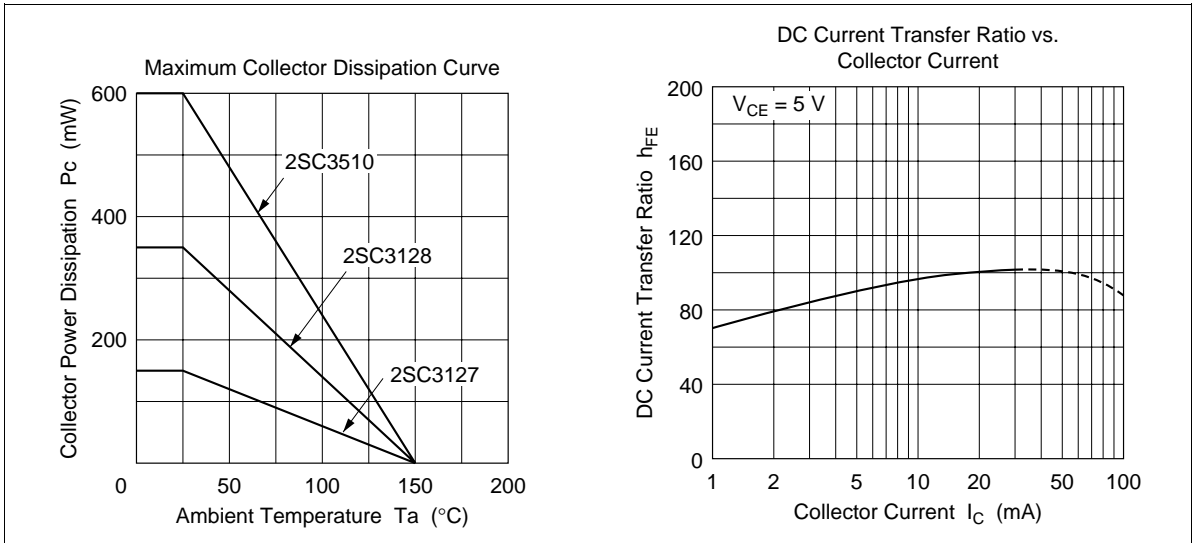
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

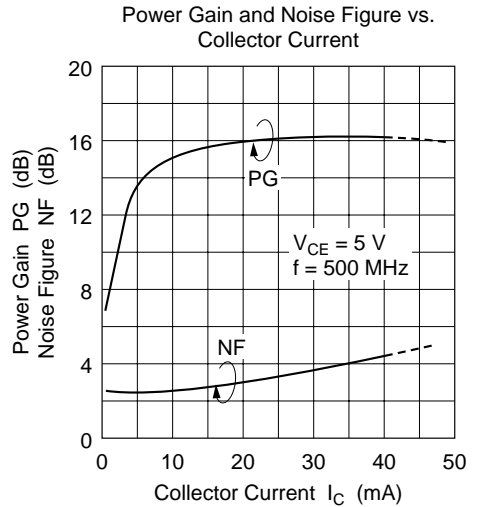
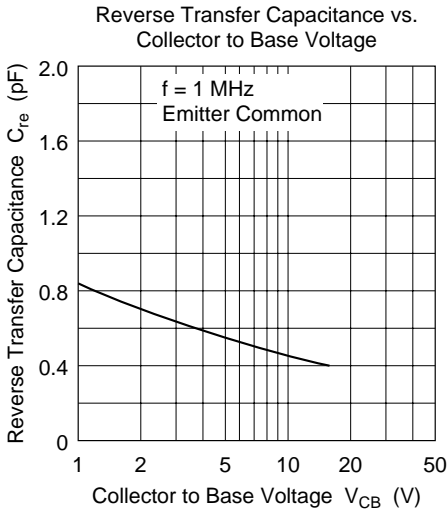
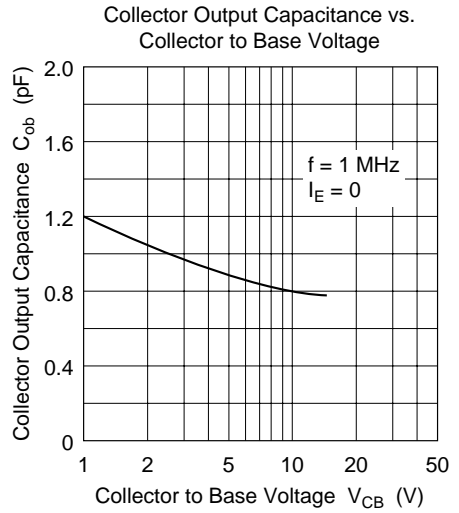
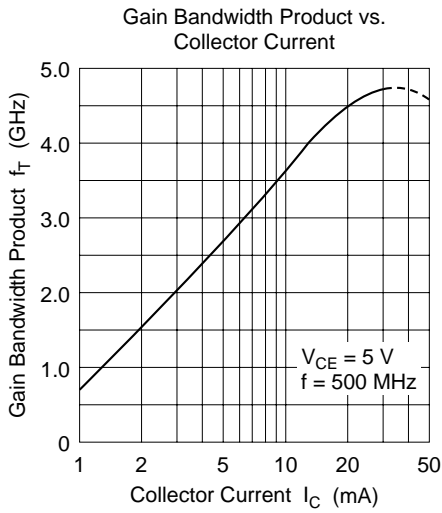
Item	Symbol	2SC3127* ¹	2SC3128	2SC3510	Unit
Collector to base voltage	V_{CBO}	20	20	20	V
Collector to emitter voltage	V_{CEO}	12	12	12	V
Emitter to base voltage	V_{EBO}	3	3	3	V
Collector current	I_{C}	50	50	50	mA
Collector power dissipation	P_{C}	150	350	600	mW
Junction temperature	T_{j}	150	150	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	-55 to +150	-55 to +150	$^\circ\text{C}$

Note: 1. Marking for 2SC3127 is "ID-".

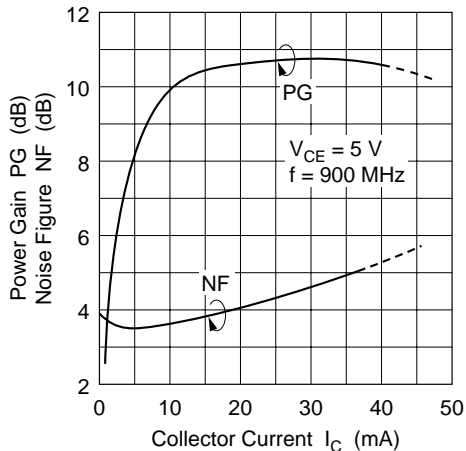
Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	20	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	12	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{EB} = 3 \text{ V}, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 12 \text{ V}, I_E = 0$
DC current transfer ratio	h_{FE}	30	90	200		$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}$
Collector output capacitance	Cob	—	0.9	1.5	pF	$V_{CB} = 5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f_T	3.5	4.5	—	GHz	$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}$
Power gain	PG	—	10.5	—	dB	$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}, f = 900 \text{ MHz}$
Noise figure	NF	—	2.2	—	dB	$V_{CE} = 5 \text{ V}, I_C = 5 \text{ mA}, f = 900 \text{ MHz}$

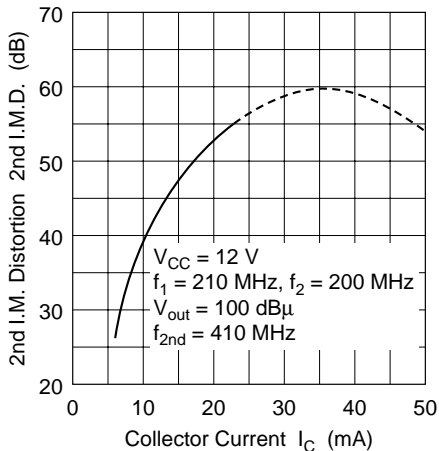




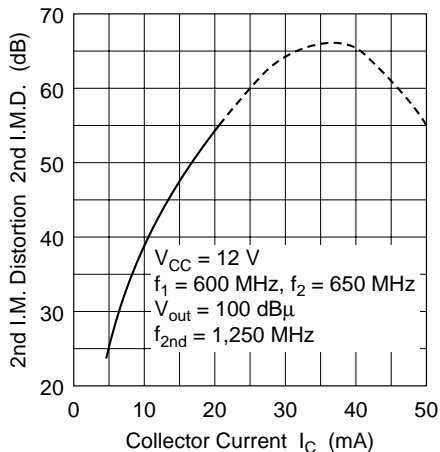
Power Gain and Noise Figure vs. Collector Current



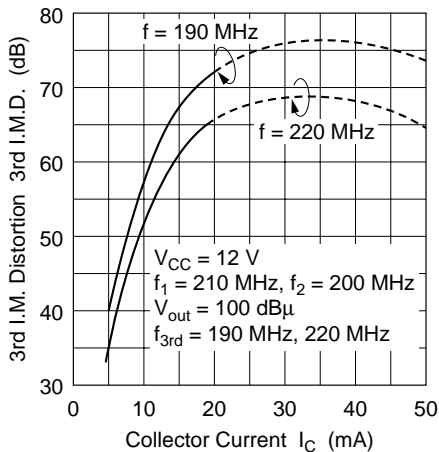
2nd I.M. Distortion vs. Collector Current

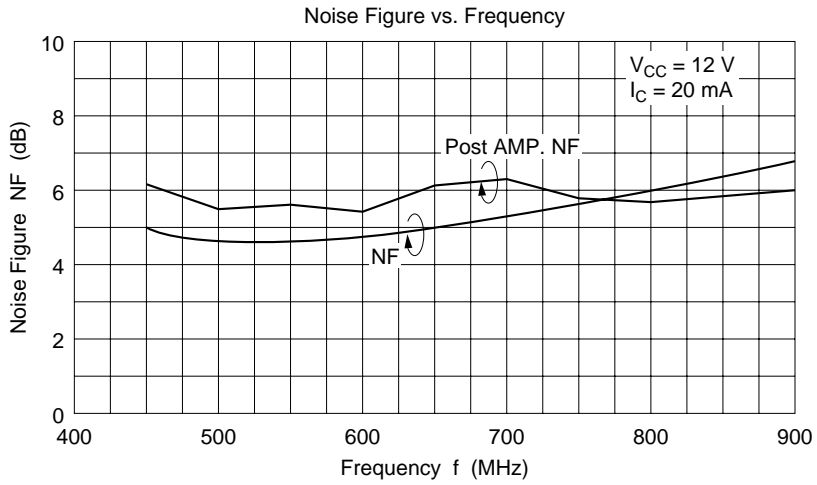
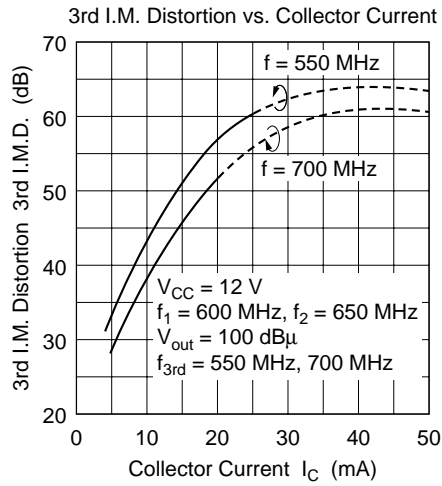


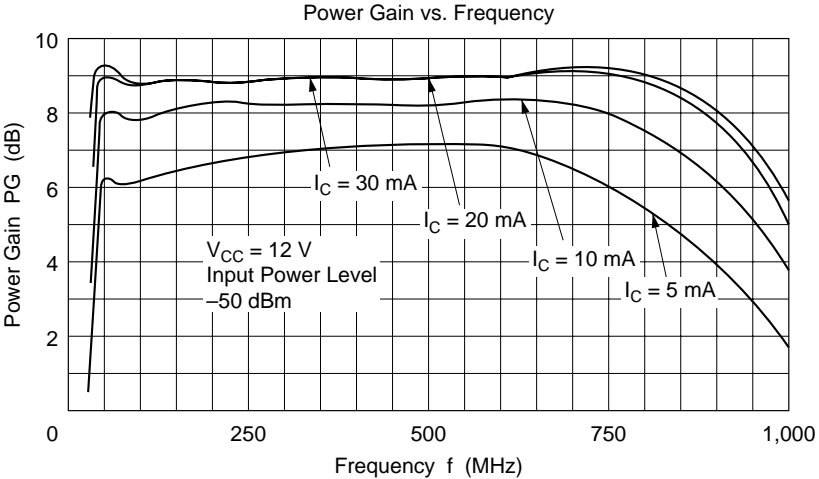
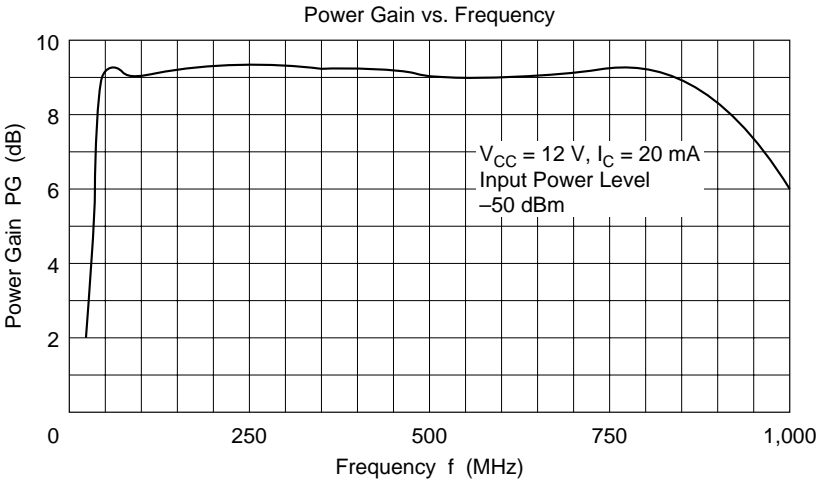
2nd I.M. Distortion vs. Collector Current

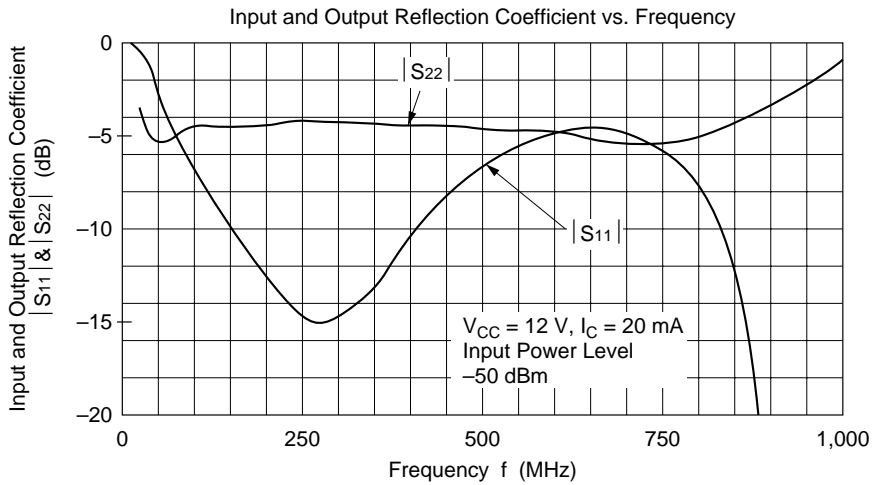


3rd I.M. Distortion vs. Collector Current

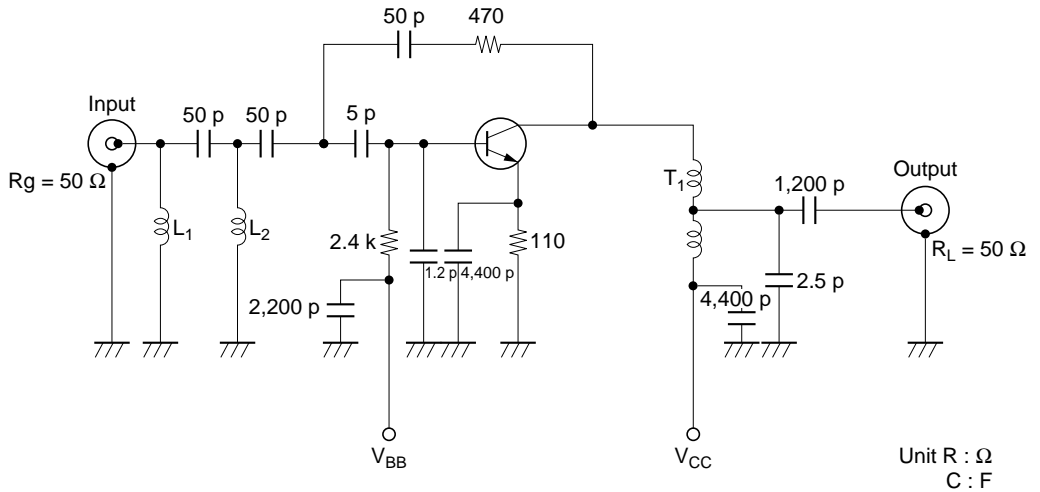








Vhf to Uhf Wide Band Amp. Circuit



Parts Specification

L_1 : Inside dia $\phi 3.0$ mm, $\phi 0.4$ mm Polyurethane Coated Copper wire 12 Turns.

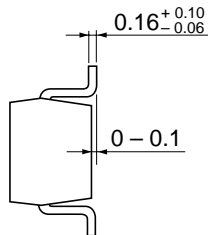
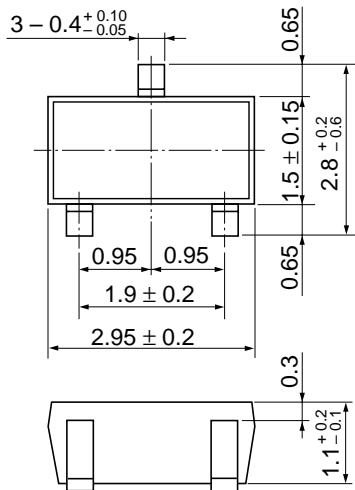
L_2 : Inside dia $\phi 3.5$ mm, $\phi 0.5$ mm Polyurethane Coated Copper wire 9 Turns.

T_1 : Balance wind used Ferrite Core

Outside dia $\phi 4.0$ mm, Inside dia $\phi 2.0$ mm

$\phi 0.1$ mm Polyurethane Coated Copper wire 3 Turns.

Ratio Input to Output is 2 : 1



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.011 g

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